# **General Purpose Transistors**

## **PNP Silicon**

#### **Features**

• These are Pb-Free Devices\*

#### **MAXIMUM RATINGS**

| Rating   | Symbol                            | Value       | Unit        |
|--|-----------------------------------|-------------|-------------|
| Collector - Emitter Voltage  | $V_{CEO}$                         | -60         | Vdc         |
| Collector - Base Voltage   | V <sub>CBO</sub>                  | -60         | Vdc         |
| Emitter - Base Voltage   | V <sub>EBO</sub>                  | -5.0        | Vdc         |
| Collector Current - Continuous                                     | Ic                                | -600        | mAdc        |
| Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C | P <sub>D</sub>                    | 625<br>5.0  | mW<br>mW/°C |
| Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C | P <sub>D</sub>                    | 1.5<br>12   | W<br>mW/°C  |
| Operating and Storage Junction<br>Temperature Range                | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

#### THERMAL CHARACTERISTICS

| Characteristic                          | Symbol          | Max  | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 200  | °C/W |
| Thermal Resistance, Junction-to-Case    | $R_{\theta JC}$ | 83.3 | °C/W |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

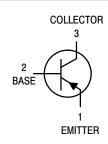
#### **DEVICE MARKING**

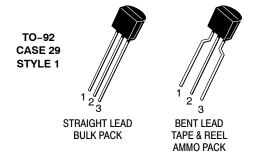
| Device        | Line 1 | Line 2 |
|---------------|--------|--------|
| MPS2907AG     | MPS    | 2907A  |
| MPS2907ARLG   | MPS2   | 907A   |
| MPS2907ARLRAG | MPS    | 2907   |
| MPS2907ARLRPG | MPS    | 2907   |



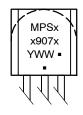
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#### **MARKING DIAGRAM**



Y = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

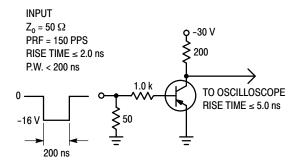
<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic  |   |                      | Min                           | Max                | Unit |
|---|---|----------------------|-------------------------------|--------------------|------|
| OFF CHARACTERISTICS   | OFF CHARACTERISTICS                                     |                      |                               |                    |      |
| Collector – Emitter Breakdown Voltage (Note 1) (I <sub>C</sub> = –10 mAdc, I <sub>B</sub> = 0)                                  |   |                      | -60                           | -                  | Vdc  |
| Collector – Base Breakdown Voltage (I <sub>C</sub>  | ; = -10 μAdc, I <sub>E</sub> = 0)                       | V <sub>(BR)CBO</sub> | -60                           | -                  | Vdc  |
| Emitter – Base Breakdown Voltage (I <sub>E</sub> =  | -10 μAdc, I <sub>C</sub> = 0)                           | V <sub>(BR)EBO</sub> | -5.0                          | -                  | Vdc  |
| Collector Cutoff Current (V <sub>CE</sub> = -30 Vd  | c, V <sub>EB(off)</sub> = -0.5 Vdc)                     | I <sub>CEX</sub>     | -                             | -50                | nAdc |
| Collector Cutoff Current $(V_{CB} = -50 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -50 \text{ Vdc}, I_E = 0, T_A = 150^{\circ}\text{C})$ |   | Ісво                 | -<br>-                        | -0.01<br>-10       | μAdc |
| Base Current (V <sub>CE</sub> = -30 Vdc, V <sub>EB(off)</sub>   | = -0.5 Vdc)   | I <sub>B</sub>       | -                             | -50                | nAdc |
| ON CHARACTERISTICS  |   | •                    | •                             | •                  | •    |
| DC Current Gain   |   | h <sub>FE</sub>      | 75<br>100<br>100<br>100<br>50 | -<br>-<br>-<br>300 | -    |
| Collector – Emitter Saturation Voltage (Note 1) ( $I_C$ = -150 mAdc, $I_B$ = -15 mAdc) ( $I_C$ = -500 mAdc, $I_B$ = -50 mAdc)   |   | V <sub>CE(sat)</sub> | -<br>-                        | -0.4<br>-1.6       | Vdc  |
| Base – Emitter Saturation Voltage (Note 1)  |   | V <sub>BE(sat)</sub> | -<br>-                        | -1.3<br>-2.6       | Vdc  |
| SMALL-SIGNAL CHARACTERISTICS  | S   |                      | !                             | 1                  |      |
| Current – Gain – Bandwidth Product (No<br>(I <sub>C</sub> = –50 mAdc, V <sub>CE</sub> = –20 Vdc, f =                            | f <sub>T</sub>  | 200                  | _                             | MHz                |      |
| Output Capacitance (V <sub>CB</sub> = -10 Vdc, I <sub>E</sub>   | C <sub>obo</sub>  | -                    | 8.0                           | pF                 |      |
| Input Capacitance (V <sub>EB</sub> = -2.0 Vdc, I <sub>C</sub>   | C <sub>ibo</sub>  | -                    | 30                            | pF                 |      |
| SWITCHING CHARACTERISTICS   |   |                      |                               |                    |      |
| Turn-On Time  | $(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc},$   | t <sub>on</sub>      | _                             | 45                 | ns   |
| Delay Time  | $I_{B1} = -15$ mAdc) (Figures 1 and 5)                  | t <sub>d</sub>       | -                             | 10                 | ns   |
| Rise Time   |   | t <sub>r</sub>       | -                             | 40                 | ns   |
| Turn-Off Time   | $(V_{CC} = -6.0 \text{ Vdc}, I_C = -150 \text{ mAdc},$  | t <sub>off</sub>     | -                             | 100                | ns   |
| Storage Time  | I <sub>B1</sub> = I <sub>B2</sub> = 15 mAdc) (Figure 2) | ts                   | -                             | 80                 | ns   |
| Fall Time   | ime   |                      | _                             | 30                 | ns   |

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 f<sub>T</sub> is defined as the frequency at which |h<sub>fe</sub>| extrapolates to unity.

INPUT



 $Z_0 = 50 \ \Omega$  PRF = 150 PPS RISE TIME  $\leq 2.0 \ ns$  P.W.  $< 200 \ ns$   $0 = 1.0 \ k$  TO OSCILLOSCOPE RISE TIME  $\leq 5.0 \ ns$   $0 = 1.0 \ k$  TO OSCILLOSCOPE RISE TIME  $\leq 5.0 \ ns$ 

Figure 1. Delay and Rise Time Test Circuit

Figure 2. Storage and Fall Time Test Circuit

#### **TYPICAL CHARACTERISTICS**

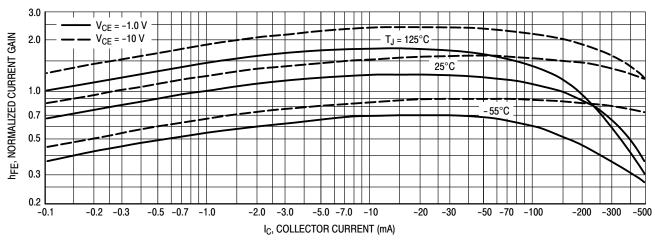


Figure 3. DC Current Gain

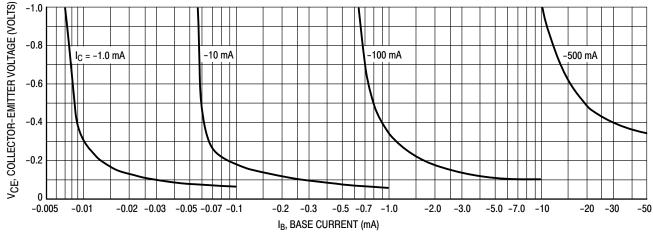


Figure 4. Collector Saturation Region

#### **ORDERING INFORMATION**

| Device        | Package            | Shipping <sup>†</sup> |  |
|---------------|--------------------|-----------------------|--|
| MPS2907AG     | TO-92<br>(Pb-Free) | 5000 Units / Bulk     |  |
| MPS2907ARLG   | TO-92<br>(Pb-Free) | 2000 / Tape & Reel    |  |
| MPS2907ARLRAG | TO-92<br>(Pb-Free) |                       |  |
| MPS2907ARLRPG | TO-92<br>(Pb-Free) | 2000 / Ammo Pack      |  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

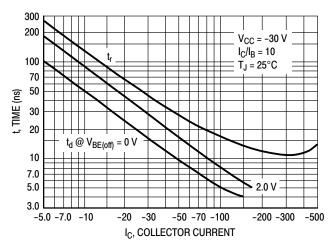


Figure 5. Turn-On Time

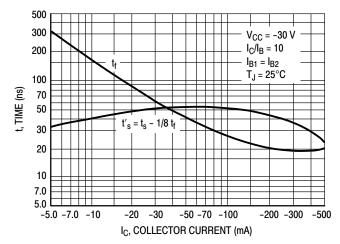


Figure 6. Turn-Off Time

# TYPICAL SMALL-SIGNAL CHARACTERISTICS

#### **NOISE FIGURE**

 $V_{CE}$  = 10 Vdc,  $T_A$  = 25°C

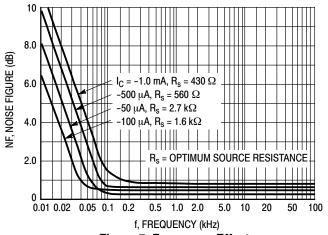


Figure 7. Frequency Effects

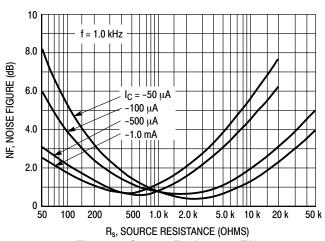


Figure 8. Source Resistance Effects

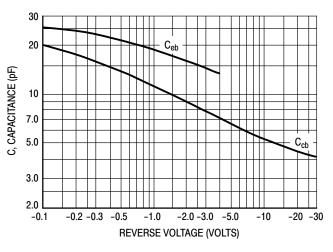


Figure 9. Capacitances

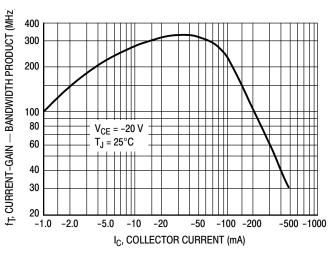


Figure 10. Current-Gain — Bandwidth Product

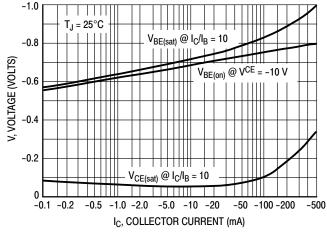


Figure 11. "On" Voltage

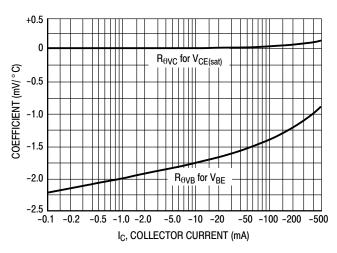
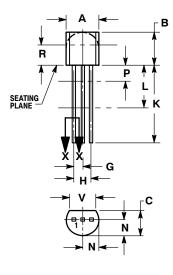


Figure 12. Temperature Coefficients

#### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM

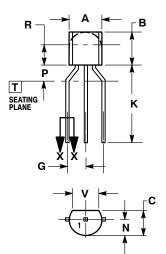


STRAIGHT LEAD **BULK PACK** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
  LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.175  | 0.205 | 4.45   | 5.20   |
| В   | 0.170  | 0.210 | 4.32   | 5.33   |
| С   | 0.125  | 0.165 | 3.18   | 4.19   |
| D   | 0.016  | 0.021 | 0.407  | 0.533  |
| G   | 0.045  | 0.055 | 1.15   | 1.39   |
| Н   | 0.095  | 0.105 | 2.42   | 2.66   |
| J   | 0.015  | 0.020 | 0.39   | 0.50   |
| K   | 0.500  |       | 12.70  |        |
| L   | 0.250  |       | 6.35   |        |
| N   | 0.080  | 0.105 | 2.04   | 2.66   |
| P   |        | 0.100 |        | 2.54   |
| R   | 0.115  |       | 2.93   |        |
| V   | 0 135  |       | 3 43   |        |



**BENT LEAD TAPE & REEL** AMMO PACK



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
  CONTOUR OF PACKAGE BEYOND
  DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | MILLIMETERS |      |  |
|-----|-------------|------|--|
| DIM | MIN         | MAX  |  |
| Α   | 4.45        | 5.20 |  |
| В   | 4.32        | 5.33 |  |
| С   | 3.18        | 4.19 |  |
| D   | 0.40        | 0.54 |  |
| G   | 2.40        | 2.80 |  |
| J   | 0.39        | 0.50 |  |
| K   | 12.70       |      |  |
| N   | 2.04        | 2.66 |  |
| P   | 1.50        | 4.00 |  |
| R   | 2.93        |      |  |
| ٧   | 3.43        |      |  |

STYLE 1:

PIN 1. EMITTER

BASE

COLLECTOR

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